

P-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}$ (Ω) Max.	I _D (A)	Q _g (Typ.)	
- 60	0.026 at V _{GS} = - 10 V	- 30 ^d	23 nC	
	0.031 at V _{GS} =-4.5 V	- 27 ^d	23110	

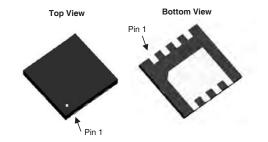
FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

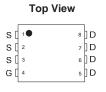
RoHS

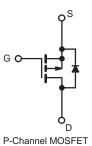
APPLICATIONS

- · Battery, Load and Adaptor Switches
 - Notebook Computers
 - Notebook Battery Packs



DFN 3x3 EP





Parameter	Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 60	V
Gate-Source Voltage		V _{GS}	± 20	V
	T _C = 25 °C		- 30 ^d	
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 70 °C	1 . [- 25 ^d	
Continuous Diam Current (1) = 130 °C)	T _A = 25 °C	l _D	-7.3 ^{a, b}	
	T _A = 70 °C	1	- 3.6 ^{a, b}	А
Pulsed Drain Current (t = 100 μs)		I _{DM}	- 120	
Continuous Source Drain Diede Current	T _C = 25 °C	I-	- 30 ^d	
Continuous Source-Drain Diode Current	T _A = 25 °C	- Is -	- 1.5 ^{a, b}	
Avalanche Current	L = 0.1 mH	I _{AS}	- 28	
Single-Pulse Avalanche Energy	L = 0.1 IIII	E _{AS}	22	mJ
	T _C = 25 °C		23.4	
Maximum Power Dissipation	T _C = 70 °C		15	w
	T _A = 25 °C	P _D	3.9 ^{a, b}	VV
	T _A = 70 °C	1 -	2.6 ^{a, b}	
Operating Junction and Storage Temperature Rang	T _J , T _{sta}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^{a, c}	t ≤ 10 s	R _{thJA}	25	30	°C/W	
Maximum Junction-to-Case	Steady State	R _{thJC}	5.3	8.5		

Notes:

- a. Surface mounted on 1" x 1" FR4 board.
- b. t = 10 s.
- c. Maximum under steady state conditions is 70 °C/W.
- d. Package limited.
- e. The DFN3X3 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
		L	1			
V _{DS}	$V_{GS} = 0, I_D = -250 \mu A$	- 60			V	
ΔV _{DS} /T _J			- 20			
$\Delta V_{GS(th)}/T_J$	I _D = - 250 μA		3.6		mV/°C	
V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	- 1		- 3	V	
I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
I _{DSS}	V _{DS} = - 48 V, V _{GS} = 0 V			- 1	μА	
	V _{DS} = - 48 V, V _{GS} = 0 V, T _J = 55 °C			- 5		
I _{D(on)}	$V_{DS} \ge -10 \text{ V}, V_{GS} = -10 \text{ V}$	- 30			Α	
R _{DS(on)}	V _{GS} = - 10 V, I _D = - 5 A		0.026	0.033	Ω	
	V _{GS} = - 4.5 V, I _D = - 5 A					
9 _{fs}	V _{DS} = - 10 V, I _D = - 5 A		25		S	
			 			
C _{iss}			1850		pF	
C _{oss}	V _{DS} = - 48 V, V _{GS} = 0 V, f = 1 MHz		590			
C _{rss}						
	V _{DS} = -48 V, V _{GS} = -10 V, I _D = -5 A		23		nC	
Q_{g}			16.4			
Q_{gs}	$V_{DS} = -48 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -5 \text{ A}$		9.5			
Q_{gd}			30.6		1	
R _g	f = 1 MHz		1.5		Ω	
t _{d(on)}			15			
t _r	$V_{DS} = -48 \text{ V}, R_L = 3.5 \Omega$ $I_D \cong -5 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		11		-	
t _{d(off)}			23			
t _f			8			
t _{d(on)}			28		ns	
t _r	$V_{DD} = -48 \text{ V}, R_{L} = 3.5 \Omega$		30		- - -	
t _{d(off)}	$I_D \cong -5 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$		22			
t _f			19			
ics			1		l	
I _S	T _C = 25 °C			- 30	A	
I _{SM}				- 120		
	I _S = -3 A, V _{GS} = 0		- 0.7	- 1.2	V	
e Q _{rr}			25		ns	
Q_{rr}	I_ = - 5 A dl/dt = 100 A/us T ₁ = 25 °C		52	<u>.</u>	nC	
t _a	$I_F = -3 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, I_J = 25 ^{\circ}\text{C}$		10		ns	
	$\begin{array}{c} \Delta V_{DS}/T_J \\ \Delta V_{GS(th)}/T_J \\ \hline V_{GS(th)} \\ \hline I_{GSS} \\ \hline I_{DSS} \\ \hline I_{D(on)} \\ \hline R_{DS(on)} \\ \hline g_{fs} \\ \hline \hline C_{iss} \\ \hline C_{oss} \\ \hline C_{rss} \\ \hline Q_g \\ \hline Q_{gd} \\ \hline R_g \\ \hline t_{d(on)} \\ \hline t_r \\ \hline t_{d(off)} \\ \hline t_f \\ \hline t_{d(off)} \\ \hline t_f \\ \hline \end{bmatrix} \\ \hline I_{SM} \\ \hline V_{SD} \\ \hline t_{rr} \\ \hline Q_{rr} \\ \hline \end{array}$	$ \begin{array}{c c} \Delta V_{DS}/T_{J} & I_{D} = -250 \mu A \\ \hline \Delta V_{GS(th)}/T_{J} & V_{DS} = V_{GS}, I_{D} = -250 \mu A \\ \hline V_{DS} = 0 V, V_{GS} = \pm 20 V \\ \hline V_{DS} = -48 V, V_{GS} = 0 V \\ \hline V_{DS} = -48 V, V_{GS} = 0 V \\ \hline V_{DS} = -48 V, V_{GS} = 0 V \\ \hline V_{DS} = -48 V, V_{GS} = 0 V, T_{J} = 55 ^{\circ}C \\ \hline V_{DS} = -48 V, V_{GS} = -10 V \\ \hline V_{DS} = -10 V, I_{D} = -5 A \\ \hline V_{GS} = -10 V, I_{D} = -5 A \\ \hline V_{GS} = -10 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{GS} = 0 V, f = 1 MHz \\ \hline C_{rss} & V_{DS} = -48 V, V_{GS} = -10 V, I_{D} = -5 A \\ \hline Q_{g} & V_{DS} = -48 V, V_{GS} = -10 V, I_{D} = -5 A \\ \hline Q_{gd} & F_{g} & f = 1 MHz \\ \hline V_{DS} = -48 V, V_{GS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{GS} = -10 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{GS} = -10 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{GS} = -10 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{GS} = -10 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{GS} = -10 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, I_{D} = -5 A \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, V_{CS} = 10 V \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, V_{CS} = 10 V \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, V_{CS} = 10 V \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, V_{CS} = 10 V \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, V_{CS} = 10 V \\ \hline V_{DS} = -48 V, V_{CS} = -4.5 V, V_{CS} = 10 V \\ \hline V_{DS} = -48 $	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	

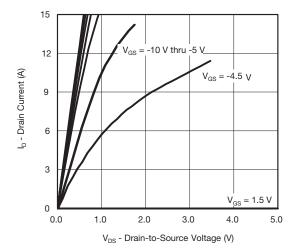
Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

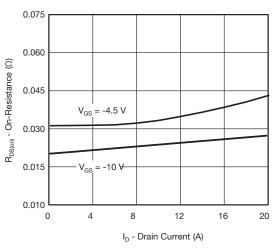
a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

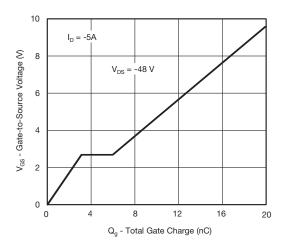




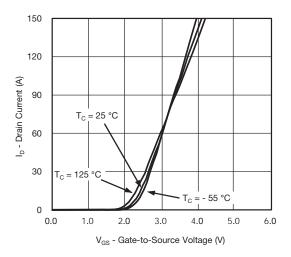
Output Characteristics



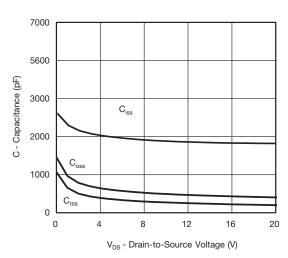
On-Resistance vs. Drain Current



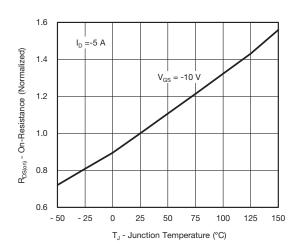
Gate Charge



Transfer Characteristics

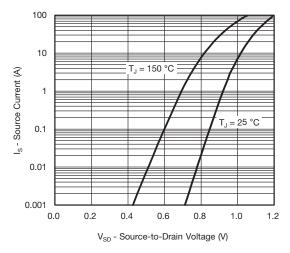


Capacitance

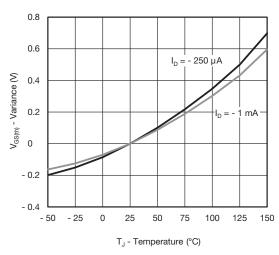


On-Resistance vs. Junction Temperature

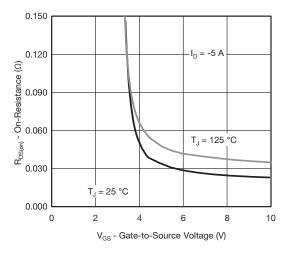




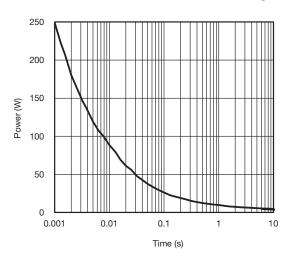
Source-Drain Diode Forward Voltage



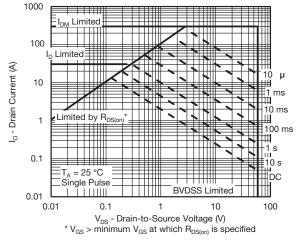
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage

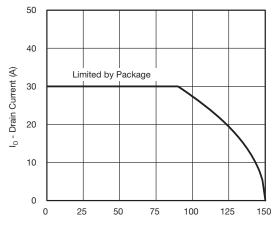


Single Pulse Power, Junction-to-Ambient



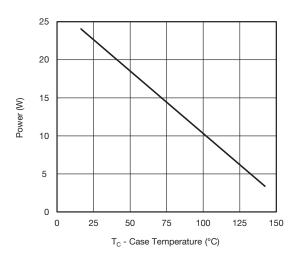
Safe Operating Area



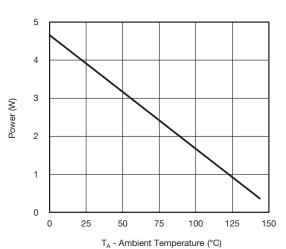


 T_{C} - Case Temperature (°C)

Current Derating*



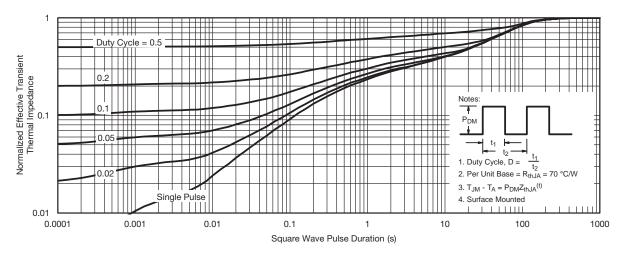




Power Derating, Junction-to-Ambient

^{*} The power dissipation P_D is based on $T_{J(max.)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit





Normalized Thermal Transient Impedance, Junction-to-Ambient



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